

Power management (dual digital transistors)

UMC3N / FMC3A

●Features

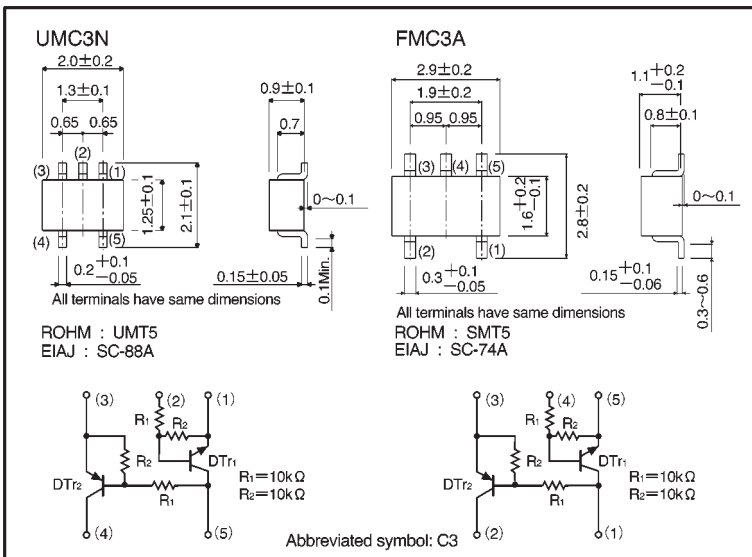
- 1) Both the DTA114E chip and DTC114E chip in a UMT or SMT package.
- 2) Ideal for power switch circuits.
- 3) Mounting cost and area can be cut in half.

●Structure

Epitaxial planar type
NPN/PNP silicon transistor
(Built-in resistor type)

The following characteristics apply to both DT_{r1} and DT_{r2} , however, the “-” sign on DT_{r2} values for the PNP type have been omitted.

●External dimensions (Units: mm)



●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Supply voltage	V_{CC}	50	V
Input voltage	V_{IN}	40	V
		-10	
Output current	I_o	50	mA
	$I_{C(\text{Max.})}$	100	
Power dissipation	UMC3N	150 (TOTAL)	mW
	FMC3A	300 (TOTAL)	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55~+150	$^\circ\text{C}$

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	0.5	V	$V_{CC}=5V, I_o=100\mu A$
	$V_{I(on)}$	3	—	—		$V_o=0.3V, I_o=10mA$
Output voltage	$V_{O(on)}$	—	0.1	0.3	V	$I_o=10mA, I_i=0.5mA$
Input current	I_i	—	—	0.88	mA	$V_i=5V$
Output current	$I_{o(off)}$	—	—	0.5	μA	$V_{CC}=50V, V_i=0V$
DC current gain	G_i	30	—	—	—	$V_o=5V, I_o=5mA$
Transition frequency	f_T	—	250	—	MHZ	$V_{CE}=10mA, I_E=-5mA, f=100MHz*$
Input resistance	R_i	7	10	13	k Ω	—
Resistance ratio	R_2/R_1	0.8	1	1.2	—	—

* Transition frequency of the device

●Packaging specifications

Part No.	Packaging type	Taping	
	Code	TR	T148
	Basic ordering unit (pieces)	3000	3000
UMC3N		○	—
FMC3A		—	○

●Electrical characteristic curves

DT_{r1} (NPN)

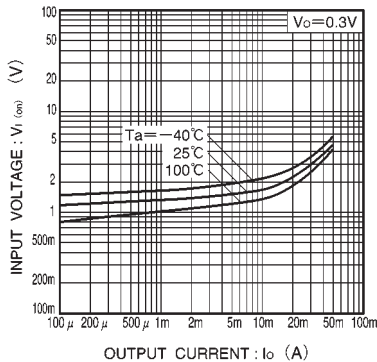


Fig.1 Input voltage vs. output current (ON characteristics)

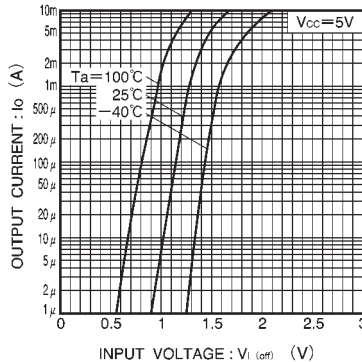


Fig.2 Output current vs. input voltage (OFF characteristics)

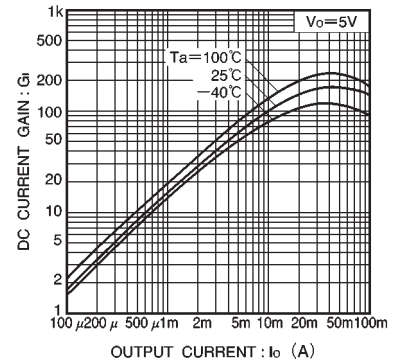


Fig.3 DC current gain vs. output current

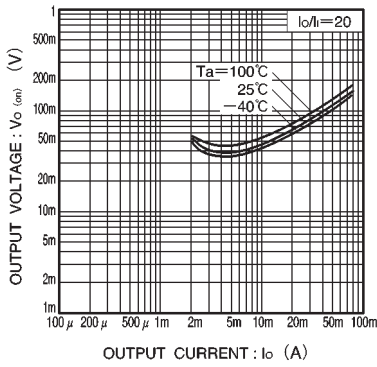


Fig.4 Output voltage vs. output current

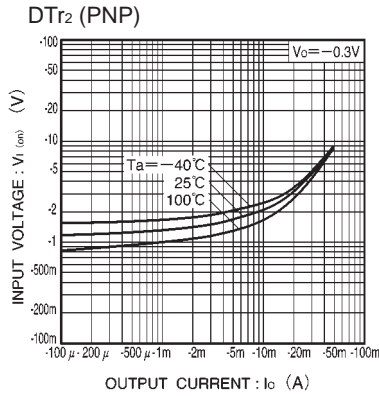


Fig.5 Input voltage vs. output current (ON characteristics)

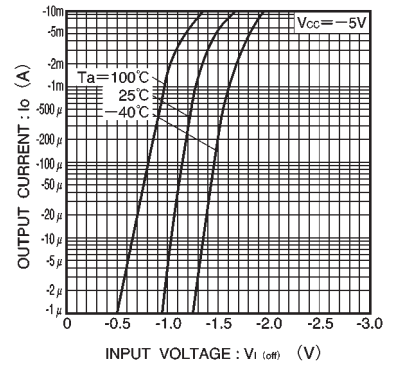


Fig.6 Output current vs. input voltage (OFF characteristics)

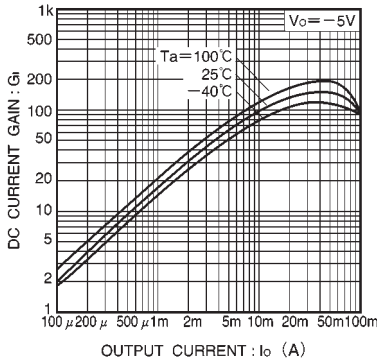


Fig.7 DC current gain vs. output current

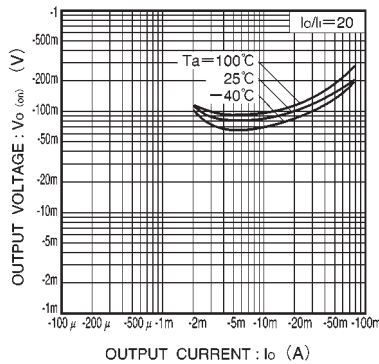


Fig.8 Output voltage vs. output current

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